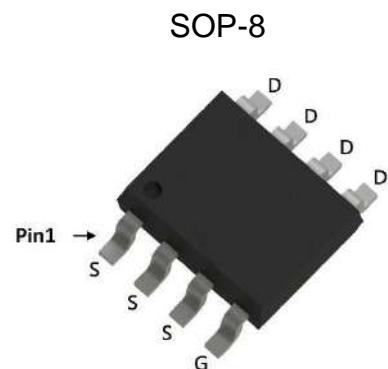


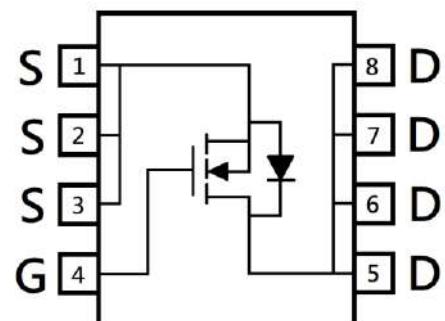
N-Channel Enhancement Mode Power MOSFET

Features:

- Low On Resistance
- Low Gate Charge
- Fast Switching Characteristic



BV _{DSS}	150V
I _D @V _{GS} =10V, T _C =25°C	15A
I _D @V _{GS} =10V, T _A =25°C	6.2A
	24mΩ



G : Gate S : Source D : Drain

Ordering Information

Device	Package	Shipping
KSCE025N15R	SOP-8 (Pb-free lead plating and halogen-free package)	4000 pcs / Tape & Reel

Absolute Maximum Ratings ($T_A=25^\circ\text{C}$)

Parameter	Symbol	Limits	Unit
Drain-Source Voltage	V _{DS}	150	V
Gate-Source Voltage	V _{GS}	±20	
Continuous Drain Current @ V _{GS} =10V, T _C =25°C	I _D	15	A
Continuous Drain Current @ V _{GS} =10V, T _C =100°C		10	
Continuous Drain Current @ V _{GS} =10V, T _A =25°C		6.2	
Continuous Drain Current @ V _{GS} =10V, T _A =70°C		5	
Pulsed Drain Current	I _{DM}	60	
Continuous Body Diode Forward Current @ T _C =25°C	I _S	13	
Avalanche Current @ L=0.1mH	I _{AS}	15	
Avalanche Energy @ L=0.5mH	E _{AS}	25	mJ
Total Power Dissipation	T _C =25°C	*a	W
	T _C =100°C	*a	
	T _A =25°C	*b	
	T _A =70°C	*b	
Operating Junction and Storage Temperature Range	T _J , T _{stg}	-55~+150	°C

Thermal Data

Parameter	Symbol	Steady State	Unit
Thermal Resistance, Junction-to-case	R _{θJC}	7.7	°C/W
Thermal Resistance, Junction-to-ambient	R _{θJA}	46	

Note:

- *a. The power dissipation P_D is based on T_{J(MAX)}=150°C, using junction-to-case thermal resistance, and is more useful in setting the upper dissipation limit for cases where additional heatsinking is used.
- *b. The value of R_{θJA} is measured with the device mounted on 1 in² FR -4 board with 2 oz. copper, in a still air environment with T_A=25°C. The power dissipation P_D is based on R_{θJA} and the maximum allowed junction temperature of 150°C. The value in any given application depends on the user's specific board design.
- *c. Repetitive rating, pulse width limited by junction temperature T_{J(MAX)}=150°C. Ratings are based on low frequency and low duty cycles to keep initial T_J=25°C.

Electrical Characteristics ($T_A=25^\circ\text{C}$, unless otherwise specified)

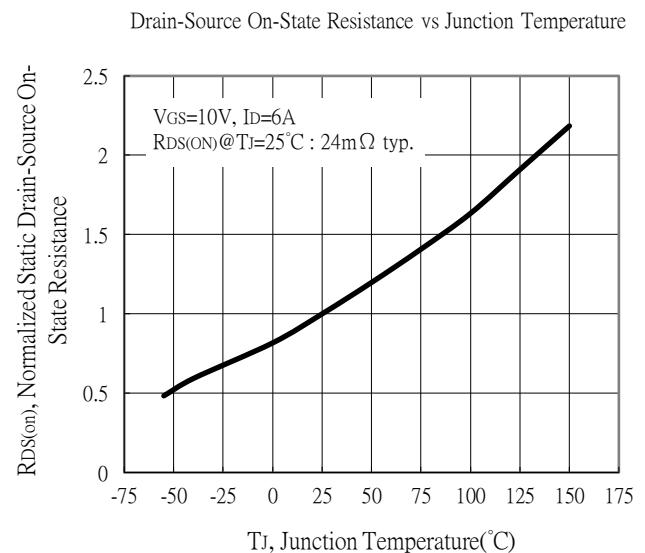
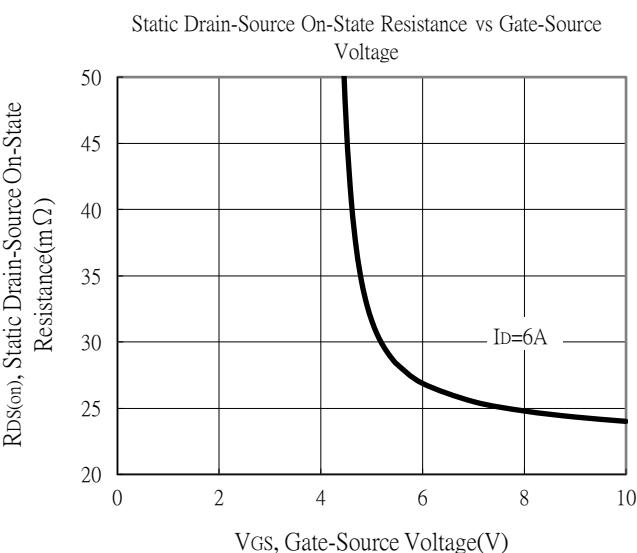
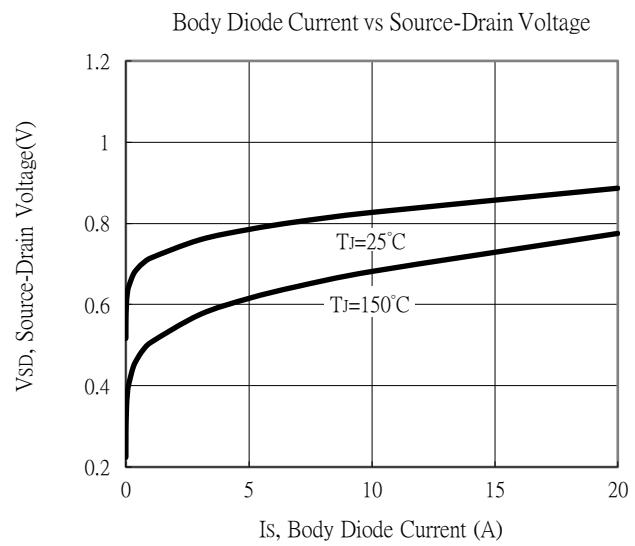
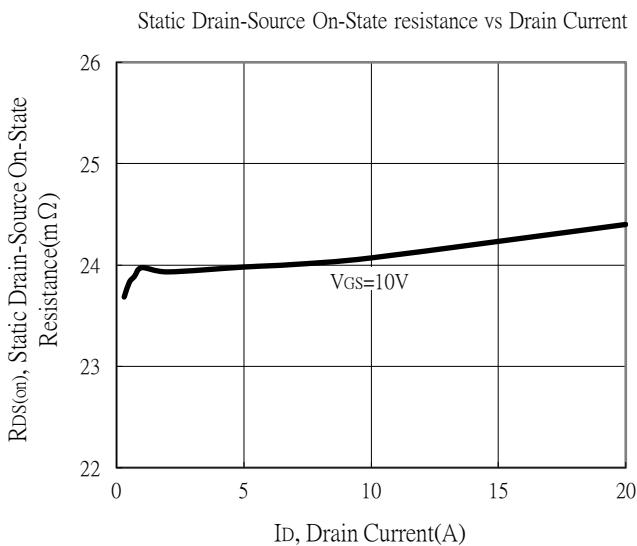
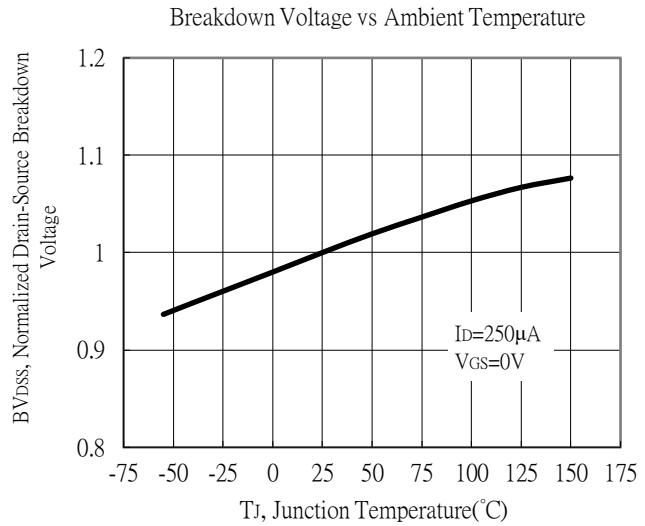
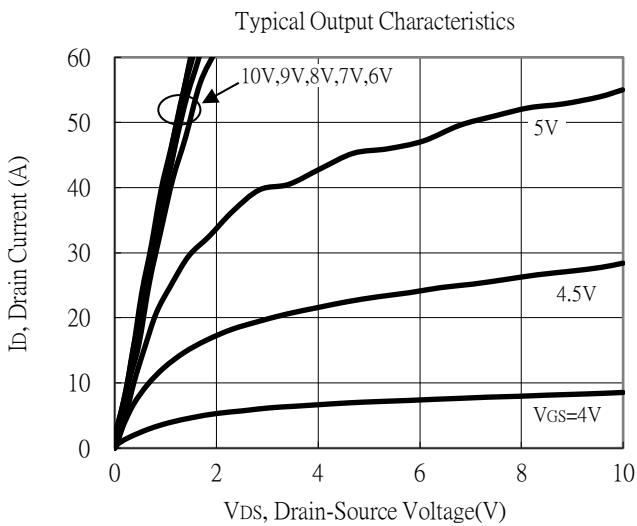
Symbol	Min.	Typ.	Max.	Unit	Test Conditions
Static					
BV _{DSS}	150	-	-	V	V _{GS} =0V, I _D =250μA
V _{GS(th)}	2	-	4		V _{DS} =V _{GS} , I _D =250μA
G _{FS}	-	13	-	S	V _{DS} =10V, I _D =6A
I _{GSS}	-	-	±100	nA	V _{GS} =±20V, V _{DS} =0V
I _{DSS}	-	-	1	μA	V _{DS} =120V, V _{GS} =0V
R _{DSS(ON)}	-	24	31	mΩ	V _{GS} =10V, I _D =6A
Dynamic					
C _{iss}	-	1904	-	pF	V _{DS} =75V, V _{GS} =0V, f=1MHz
C _{oss}	-	136	-		
C _{rss}	-	26	-		
R _g	-	0.4	-	Ω	f=1MHz
Q _g *1, 2	-	33	-	nC	V _{DS} =75V, I _D =6A, V _{GS} =10V
Q _{gs} *1, 2	-	8	-		
Q _{gd} *1, 2	-	8	-		
t _{d(ON)} *1, 2	-	19	-	ns	V _{DS} =75V, I _D =6A, V _{GS} =10V, R _{GS} =6Ω
t _r *1, 2	-	20	-		
t _{d(OFF)} *1, 2	-	35	-		
t _f *1, 2	-	20	-		
Source-Drain Diode					
V _{SD} *1	-	0.8	1.2	V	I _S =6A, V _{GS} =0V
tr	-	61	-	ns	I _F =6A, dI _F /dt=100A/μs
Q _{rr}	-	155	-	nC	

Note:

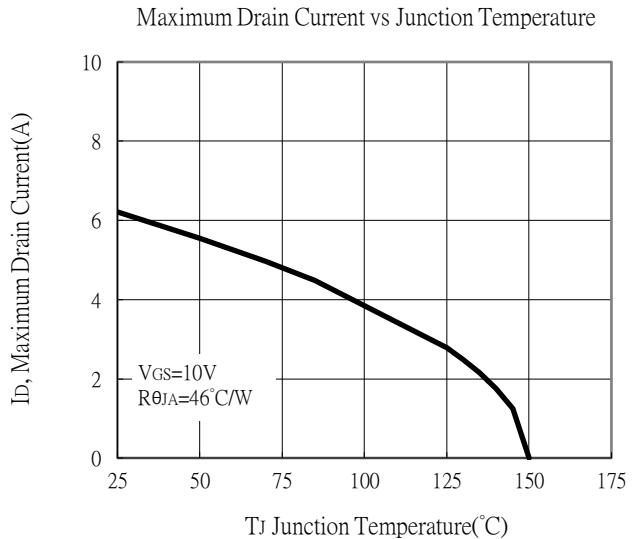
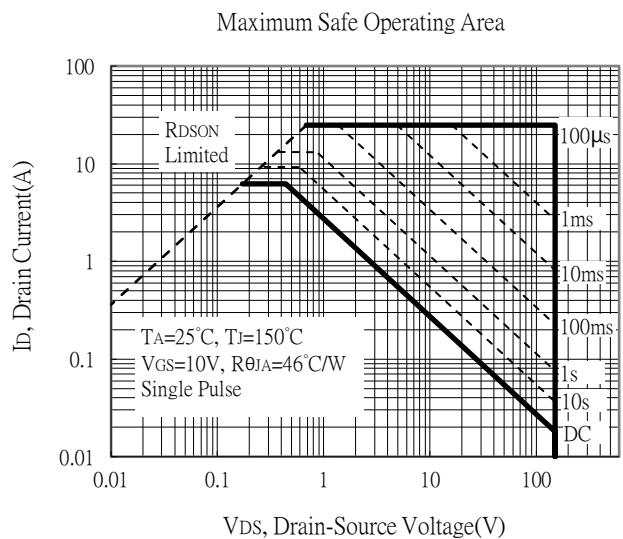
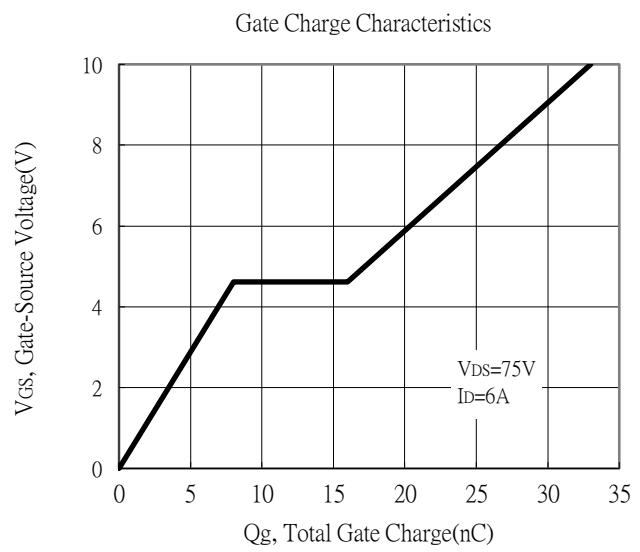
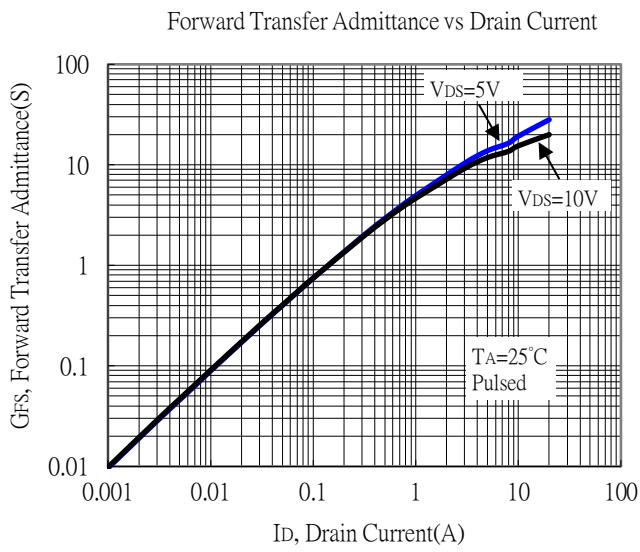
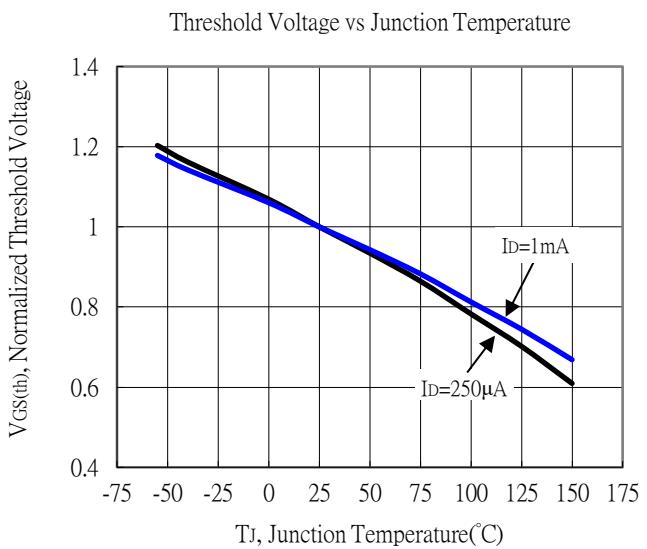
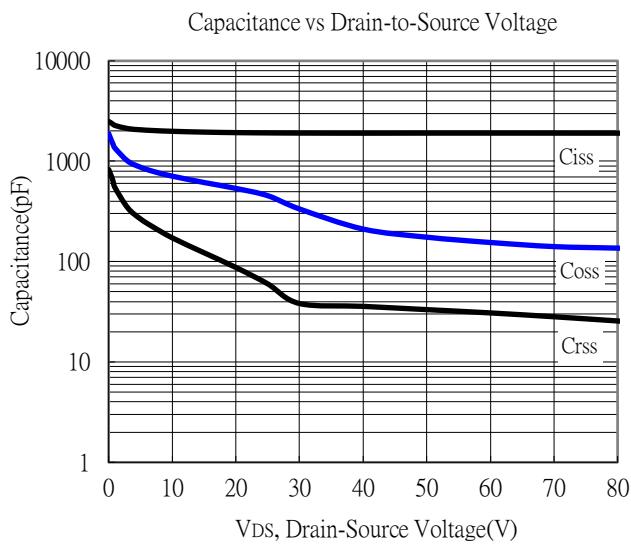
*1. Pulse Test : Pulse Width ≤300μs, Duty Cycle≤2%

*2. Independent of operating temperature

Typical Characteristics

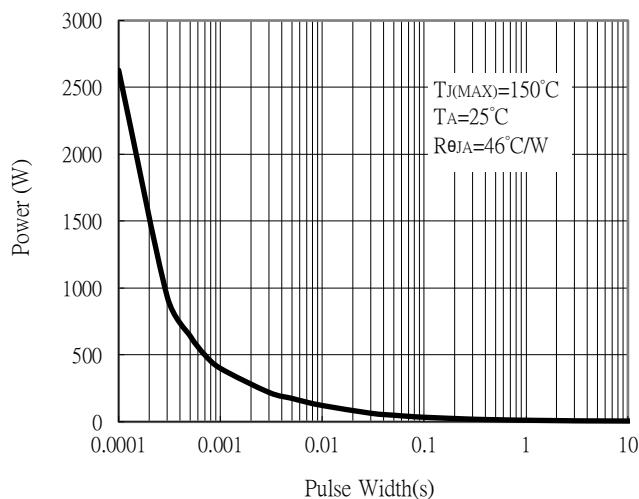


Typical Characteristics (Cont.)

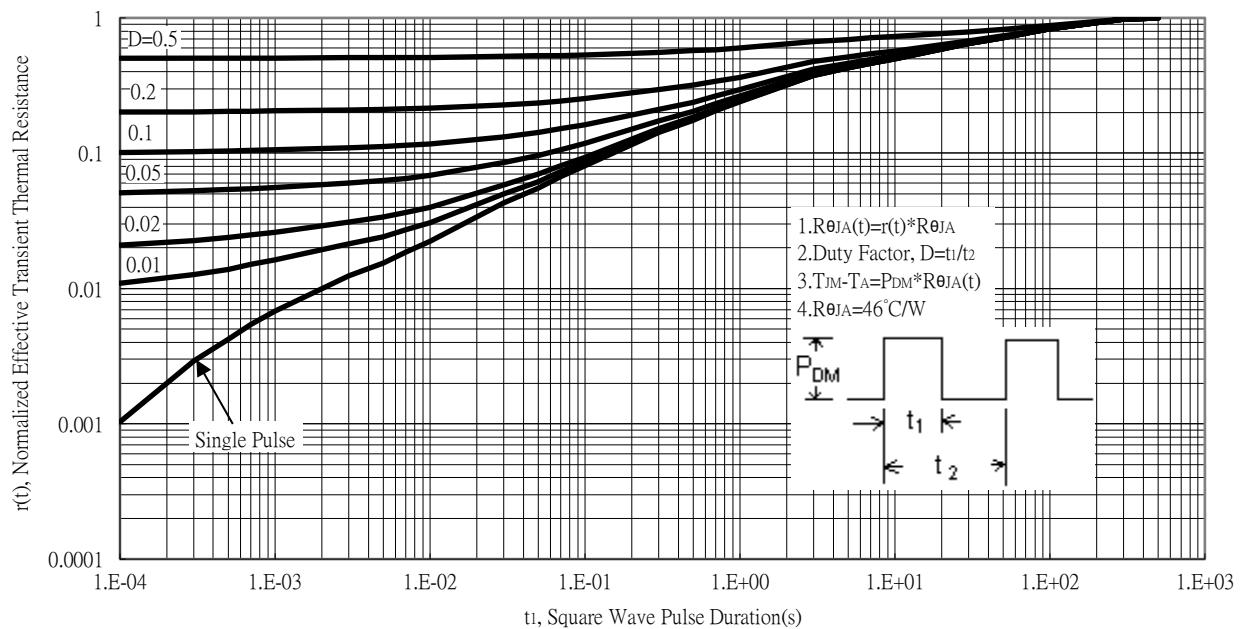


Typical Characteristics (Cont.)

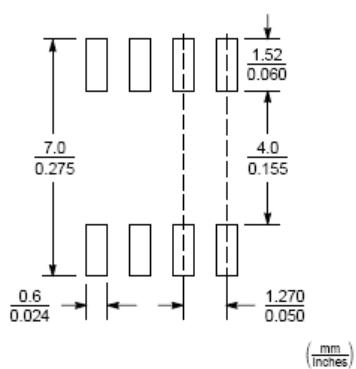
Single Pulse Power Rating, Junction to Ambient



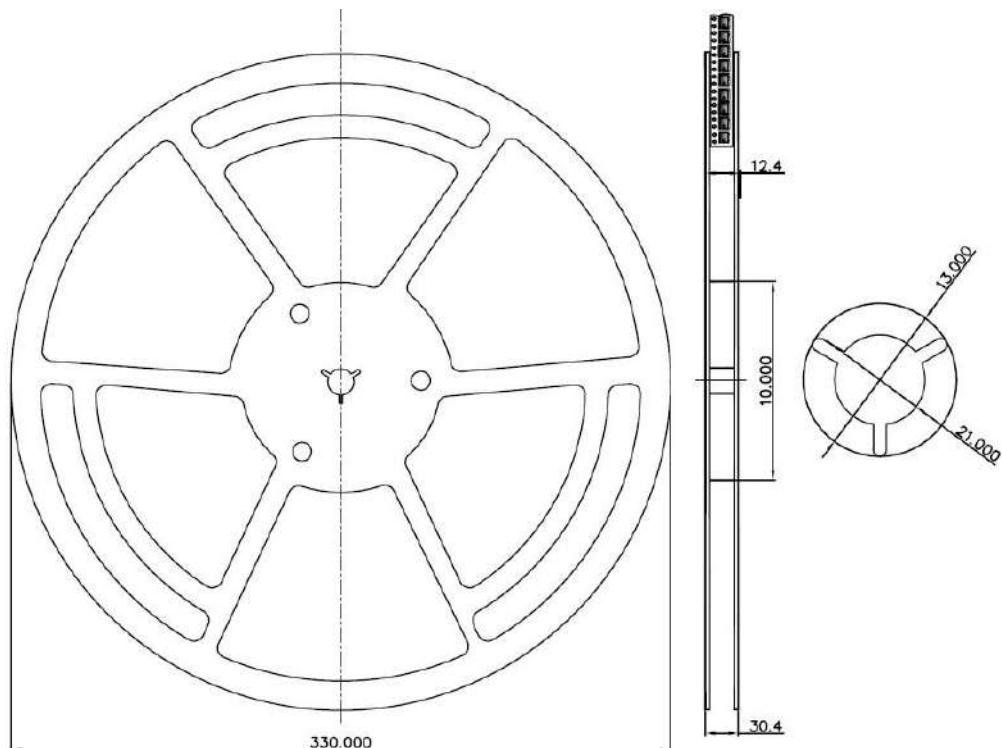
Transient Thermal Response Curves



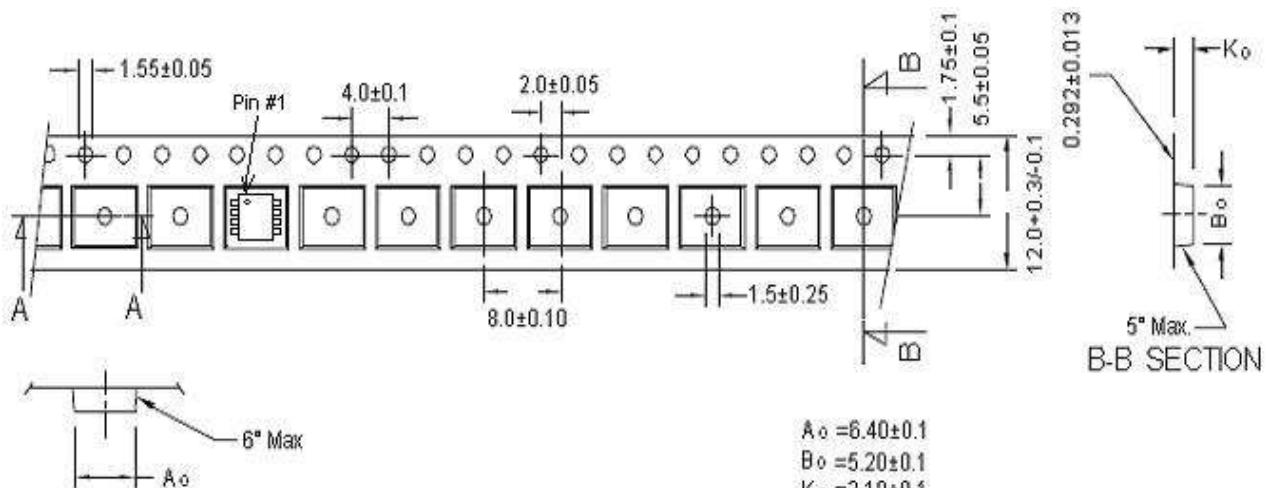
Recommended Soldering Footprint



Reel Dimension



Carrier Tape Dimension



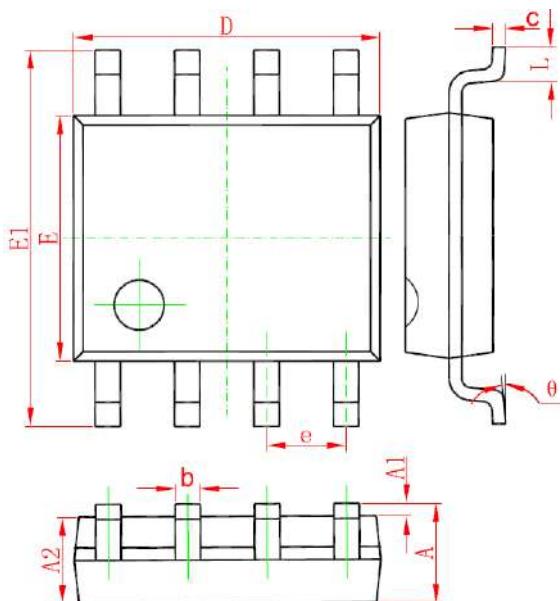
A-A SECTION

Notes:

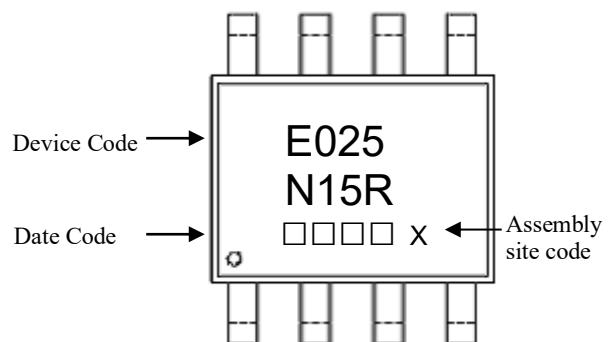
1. 10 sprocket hole pitch cumulative tolerance ± 0.2 .
2. Camber not to exceed 1mm in 100mm.
3. Material: conductive black polystyrene
4. Ao & Bo measured on a plane 0.3mm above the bottom of the pocket.
5. Ko measured from a plane on the inside bottom of the pocket to the top surface of the carrier.
6. Pocket position relative to sprocket hole measured as true position of pocket, not pocket hole.

Unit : millimeter

SOP-8 Dimension



Marking:



Date Code(counting from left to right) :

1st code: year code, the last digit of Christian year

2nd code : month code, Jan→A, Feb→B, Mar→C, Apr→D

May→E, Jun→F, Jul→G, Aug→H, Sep→J,

Oct→K, Nov→L, Dec→M

3rd and 4th codes : production serial number, 01~99

Assembly site code : blank→ site 1, G →site 2

8-Lead SOP-8 Plastic Package

*: Typical

DIM	Millimeters		Inches		DIM	Millimeters		Inches	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
A	1.350	1.750	0.053	0.069	E	3.800	4.000	0.150	0.157
A1	0.100	0.250	0.004	0.010	E1	5.800	6.200	0.228	0.244
A2	1.350	1.550	0.053	0.061	e	*1.270		*0.050	
b	0.330	0.510	0.013	0.020	L	0.400	1.270	0.016	0.050
c	0.170	0.250	0.006	0.010	θ	0°	8°	0°	8°
D	4.700	5.100	0.185	0.200					